# /N/IXI/N Switched-Capacitor Voltage Inverters

## **General Description**

Applications

The ultra-small MAX870/MAX871 monolithic, CMOS charge-pump inverters accept input voltages ranging from +1.4V to +5.5V. The MAX870 operates at 125kHz, and the MAX871 operates at 500kHz. Their high efficiency (90%) and low operating current (0.7mA for the MAX870) make these devices ideal for both battery-powered and board-level voltage-conversion applications.

Oscillator control circuitry and four power MOSFET switches are included on-chip. A typical MAX870/ MAX871 application is generating a -5V supply from a +5V logic supply to power analog circuitry. Both parts come in a 5-pin SOT23-5 package and can deliver 25mA with a voltage drop of 500mV.

For applications requiring more power, the MAX860 delivers up to 50mA with a voltage drop of 600mV, in a space-saving µMAX package.

Small LCD Panels

Medical Instruments

Handy-Terminals, PDAs

Battery-Operated Equipment

**Cell Phones** 

C1+

C1-

GND

<u>+</u>

Local -5V Supply from 5V Logic Supply

IN

OUT

1/XI//

MAX870

MAX871

**NEGATIVE VOLTAGE CONVERTER** 

Features

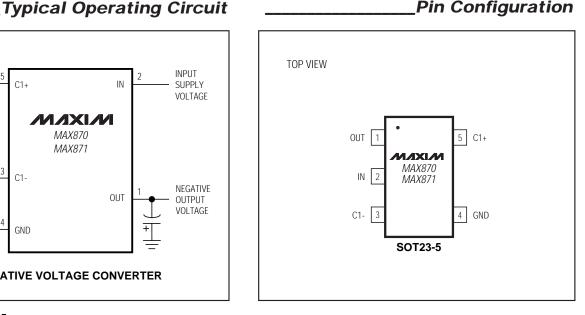
- 5-Pin SOT23-5 Package
- ♦ 99% Voltage Conversion Efficiency
- Invert Input Supply Voltage
- O.7mA Quiescent Current (MAX870)
- +1.4V to +5.5V Input Voltage Range
- Require Only Two Capacitors
- 25mA Output Current
- Shutdown Control

### Ordering Information

PART	TEMP. RANGE	PIN- PACKAGE	SOT TOP MARK
MAX870C/D	$0^{\circ}C$ to $+70^{\circ}C$	Dice*	—
MAX870EUK	-40°C to +85°C	5 SOT23-5	ABZN
MAX871C/D	$0^{\circ}C$ to $+70^{\circ}C$	Dice*	—
MAX871EUK	-40°C to +85°C	5 SOT23-5	ABZO

\* Dice are tested at  $T_A = +25^{\circ}C$ .

## Pin Configuration



## 

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## **ABSOLUTE MAXIMUM RATINGS**

IN to GND+6.0V to -0.3V OUT to GND6.0V to +0.3V	Continuous Power Dissipation (T <sub>A</sub> = +70°C) SOT23-5 (derate 7.1mW/°C above +70°C)571mW
C1+(V <sub>IN</sub> + 0.3V) to -0.3V	Operating Temperature Range
C1(V <sub>OUT</sub> - 0.3V) to +0.3V	MAX870EUK/MAX871EUK40°C to +85°C
OUT Output Current	Storage Temperature Range65°C to +160°C
OUT Short Circuit to GNDIndefinite	Lead Temperature (soldering, 10sec)+300°C

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

### **ELECTRICAL CHARACTERISTICS**

 $(V_{IN} = +5V, C1 = C2 = 1\mu F \text{ (MAX870)}, C1 = C2 = 0.33\mu F \text{ (MAX871)}, T_A = 0°C \text{ to } +85°C, unless otherwise noted. Typical values are at T_A = +25°C.)$ 

PARAMETER		C	ONDITION	NS I		MIN	TYP	MAX	UNITS	
Supply Current	т	Τ		MA	X870		0.7	1.0		
Supply Current	IA = +	$T_A = +25^{\circ}C$			X871		2.7	3.8	- mA	
Minimum Supply Voltage	DLOAD			TA =	= +25°C	1.4	1.0		V	
winimum supply voltage	KLOAD	$R_{LOAD} = 10k\Omega$			= 0°C to + 85°C	1.5			- V	
Maximum Supply Voltage	Rload	= 10kΩ						5.5	V	
Oscillator Frequency	т.	T. DE°C		MA	X870	81	125	169	- kHz	
Oscillator Frequency	IA = +	$T_A = +25^{\circ}C$			X871	325	500	675		
Power Efficiency	RLOAD	$R_{LOAD} = 500 k \Omega$ ,		MA	X870		90		%	
Fower Enclency	T <sub>A</sub> =+2	T <sub>A</sub> =+25°C			X871		75		1 10	
Voltage Conversion Efficiency	RIGAD	R <sub>LOAD</sub> = ∞, T <sub>A</sub> =+25°C		MA	X870	98	98 99.3		%	
Voltage Conversion Enciency	NLOAD	$R_{LOAD} = \infty, R_{A} = +25 \text{ C}$			X871	96	99			
	) 5mA	T <sub>A</sub> = +25°C	MAX870	,	$C1 = C2 = 1\mu F$		20	50		
				,	$C1 = C2 = 0.47 \mu F$		25			
Output Resistance (Note 1)					$C1 = C2 = 0.33 \mu F$		20	50	Ω	
Output Resistance (Note 1)			MAX871		$C1 = C2 = 0.22 \mu F$		25		32	
				$C1 = C2 = 0.1 \mu F$			35			
		$T_{A} = 0^{\circ}C \text{ to } + 8$		°C				65		

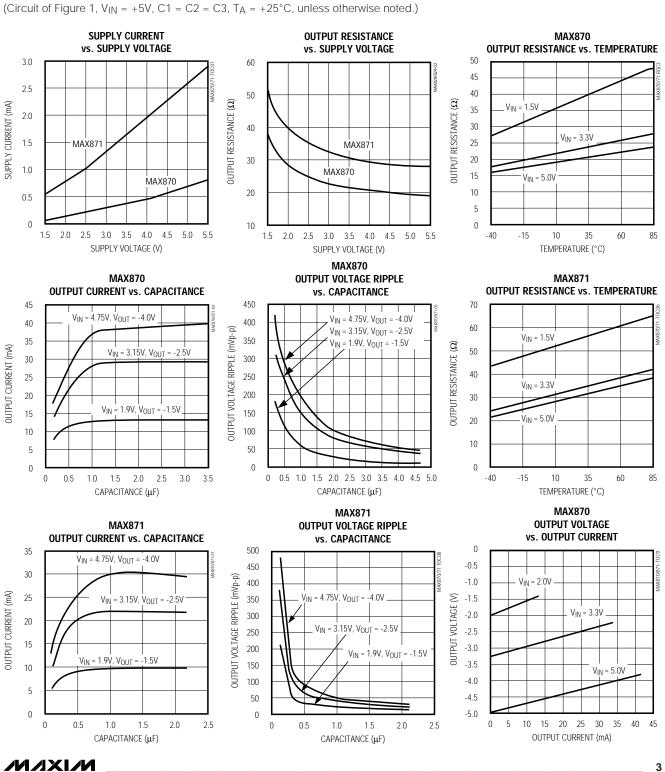
Note 1: Capacitor contribution is approximately 20% of the output impedance [ESR + 1 / (pump frequency x capacitance)].

### **ELECTRICAL CHARACTERISTICS**

 $(V_{IN} = +5V, C1 = C2 = 1\mu F (MAX870), C1 = C2 = 0.33\mu F (MAX871), T_A = -40^{\circ}C to +85^{\circ}C$ , unless otherwise noted.) (Note 2)

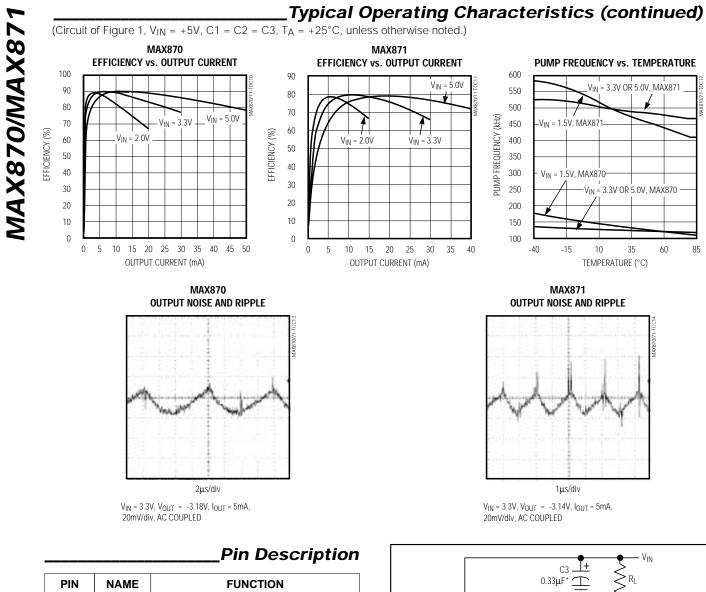
PARAMETER	CONDITIONS			TYP	MAX	UNITS	
Supply Current	MAX870			1.3	mA		
Supply Current	MAX871			4.4			
Minimum Supply-Voltage Range	$R_{LOAD} = 10k\Omega$		1.6			V	
Maximum Supply-Voltage Range	$R_{LOAD} = 10k\Omega$	$R_{LOAD} = 10k\Omega$			5.5	V	
Oscillator Frequency	MAX870	56		194	kHz		
	MAX871	225		775			
Output Resistance	I <sub>OUT</sub> = 5mA			65	Ω		
Voltage Conversion Efficiency	RLOAD = ∞	MAX870	97			%	
voltage conversion Enciency		MAX871	95			/0	

Note 2: All -40°C to +85°C specifications are guaranteed by design.



## **Typical Operating Characteristics**

MAX870/MAX871



PIN	NAME	FUNCTION			
1	OUT	Inverting Charge-Pump Output			
2	IN	Positive Power-Supply Input			
3	C1-	Flying Capacitor's Negative Terminal			
4	GND	Ground			
5	C1+	Flying Capacitor's Positive Terminal			

Figure 1. Test Circuit

\*1µF (MAX870) OUT

C1

///////////

IN MAX870 MAX871

C1+

GNF

**VOLTAGE INVERTER** 

↓ C2 + 0.33µF\*

VOUT

C1

0.33µF\*

### \_Detailed Description

The MAX870/MAX871 capacitive charge pumps invert the voltage applied to their input. For highest performance, use low equivalent series resistance (ESR) capacitors (e.g., ceramic).

During the first half-cycle, switches S2 and S4 open, switches S1 and S3 close, and capacitor C1 charges to the voltage at IN (Figure 2). During the second half-cycle, S1 and S3 open, S2 and S4 close, and C1 is level shifted downward by  $V_{IN}$  volts. This connects C1 in parallel with the reservoir capacitor C2. If the voltage across C2 is smaller than the voltage across C1, then charge flows from C1 to C2 until the voltage across C2 reaches -VIN. The actual voltage at the output is more positive than -VIN, since switches S1–S4 have resistance and the load drains charge from C2.

#### **Charge-Pump Output**

The MAX870/MAX871 are not voltage regulators: the charge pump's output source resistance is approximately  $20\Omega$  at room temperature (with V<sub>IN</sub> = +5V), and V<sub>OUT</sub> approaches -5V when lightly loaded. V<sub>OUT</sub> will droop toward GND as load current increases. The droop of the negative supply (V<sub>DROOP</sub>-) equals the current draw from OUT (I<sub>OUT</sub>) times the negative converter's source resistance (RS-):

VDROOP- = IOUT X RS-

The negative output voltage will be:

VOUT = -(VIN - VDROOP)

#### **Efficiency Considerations**

The power efficiency of a switched-capacitor voltage converter is affected by three factors: the internal losses in the converter IC, the resistive losses of the pump capacitors, and the conversion losses during charge transfer between the capacitors. The total power loss is:

 $\Sigma P_{LOSS} = P_{INTERNAL LOSSES} + P_{SWITCH LOSSES}$ 

- + P PUMP CAPACITOR LOSSES
- + PCONVERSION LOSSES

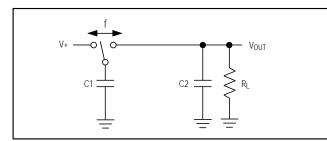


Figure 3a. Switched-Capacitor Model

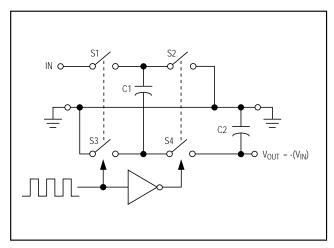


Figure 2. Ideal Voltage Inverter

The internal losses are associated with the IC's internal functions, such as driving the switches, oscillator, etc. These losses are affected by operating conditions such as input voltage, temperature, and frequency.

The next two losses are associated with the voltage converter circuit's output resistance. Switch losses occur because of the on-resistance of the MOSFET switches in the IC. Charge-pump capacitor losses occur because of their ESR. The relationship between these losses and the output resistance is as follows:

PPUMP CAPACITOR LOSSES + PCONVERSION LOSSES  
= 
$$I_{OUT}^2 \times R_{OUT}$$
  
 $R_{OUT} \approx \frac{1}{(f_{OSC}) \times C1} + 2R_{SWITCHES} + 4ESR_{C1} + ESR_{C2}$ 

where  $f_{OSC}$  is the oscillator frequency. The first term is the effective resistance from an ideal switched-capacitor circuit. See Figures 3a and 3b.

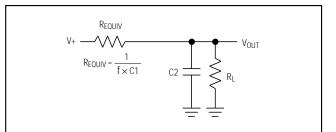


Figure 3b. Equivalent Circuit

**WAX870/MAX871** 

Conversion losses occur during the charge transfer between C1 and C2 when there is a voltage difference between them. The power loss is:

$$P_{\text{CONV.LOSS}} = \left[ \frac{1}{2} C1 \left( V_{\text{IN}}^2 - V_{\text{OUT}}^2 \right) + \frac{1}{2} C2 \left( V_{\text{RIPPLE}}^2 - 2V_{\text{OUT}} V_{\text{RIPPLE}} \right) \right] \times f_{\text{OSC}}$$

### Applications Information

#### **Capacitor Selection**

To maintain the lowest output resistance, use capacitors with low ESR (Table 1). The charge-pump output resistance is a function of C1's and C2's ESR. Therefore, minimizing the charge-pump capacitor's ESR minimizes the total output resistance.

#### Flying Capacitor (C1)

Increasing the flying capacitor's size reduces the output resistance. Small C1 values increase the output resistance. Above a certain point, increasing C1's capacitance has a negligible effect, because the output resistance becomes dominated by the internal switch resistance and capacitor ESR.

#### **Output Capacitor (C2)**

Increasing the output capacitor's size reduces the output ripple voltage. Decreasing its ESR reduces both output resistance and ripple. Smaller capacitance values can be used with light loads if higher output ripple can be tolerated. Use the following equation to calculate the peak-to-peak ripple:

$$V_{\text{RIPPLE}} = \frac{I_{\text{OUT}}}{f_{\text{OSC}} \times C2} + 2 \times I_{\text{OUT}} \times \text{ESR}_{C2}$$

#### Input Bypass Capacitor

Bypass the incoming supply to reduce its AC impedance and the impact of the MAX870/MAX871's switching noise. The recommended bypassing depends on the circuit configuration and on where the load is connected.

When the inverter is loaded from OUT to GND, current from the supply switches between 2 x I<sub>OUT</sub> and zero. Therefore, use a large bypass capacitor (e.g., equal to the value of C1) if the supply has a high AC impedance.

When the inverter is loaded from IN to OUT, the circuit draws 2 x  $I_{OUT}$  constantly, except for short switching spikes. A  $0.1\mu$ F bypass capacitor is sufficient.

#### Voltage Inverter

The most common application for these devices is a charge-pump voltage inverter (Figure 1). This application requires only two external components—capacitors C1 and C2—plus a bypass capacitor, if necessary. Refer to the *Capacitor Selection* section for suggested capacitor types.

#### **Cascading Devices**

Two devices can be cascaded to produce an even larger negative voltage (Figure 4). The unloaded output voltage is normally -2 x V<sub>IN</sub>, but this is reduced slightly by the output resistance of the first device multiplied by the quiescent current of the second. When cascading more than two devices, the output resistance rises dramatically. For applications requiring larger negative voltages, see the MAX864 and MAX865 data sheets.

#### **Paralleling Devices**

Paralleling multiple MAX870s or MAX871s reduces the output resistance. Each device requires its own pump capacitor (C1), but the reservoir capacitor (C2) serves all devices (Figure 5). Increase C2's value by a factor of n, where n is the number of parallel devices. Figure 5 shows the equation for calculating output resistance.

#### **Combined Doubler/Inverter**

In the circuit of Figure 6, capacitors C1 and C2 form the inverter, while C3 and C4 form the doubler. C1 and C3 are the pump capacitors; C2 and C4 are the reservoir

PRODUCTION METHOD	MANUFACTURER	SERIES	PHONE	FAX
	AVX	TPS series	(803) 946-0690	(803) 626-3123
Surface-Mount Tantalum	Matsuo	267 series	(714) 969-2491	(714) 960-6492
	Sprague	593D, 595D series	(603) 224-1961	(603) 224-1430
Surface-Mount	AVX	X7R	(803) 946-0690	(803) 626-3123
Ceramic	Matsuo	X7R	(714) 969-2491	(714) 960-6492

Table 1. Low-ESR Capacitor Manufacturers

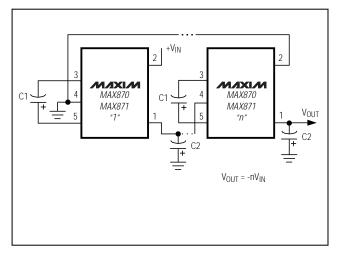


Figure 4. Cascading MAX870s or MAX871s to Increase Output Voltage

capacitors. Because both the inverter and doubler use part of the charge-pump circuit, loading either output causes both outputs to decline toward GND. Make sure the sum of the currents drawn from the two outputs does not exceed 40mA.

#### Heavy Output Current Loads

Under heavy loads, where higher supply is sourcing current into OUT, the OUT supply must not be pulled above ground. Applications that sink heavy current into OUT require a Schottky diode (1N5817) between GND and OUT, with the anode connected to OUT (Figure 7).

#### Layout and Grounding

Good layout is important, primarily for good noise performance. To ensure good layout, mount all components as close together as possible, keep traces short to minimize parasitic inductance and capacitance, and use a ground plane.

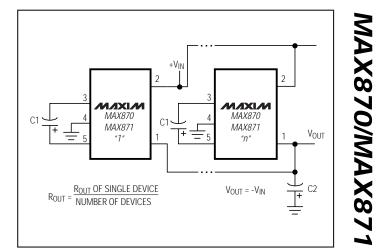


Figure 5. Paralleling MAX870s or MAX871s to Reduce Output Resistance

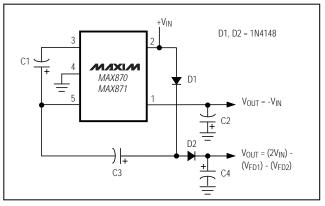


Figure 6. Combined Doubler and Inverter

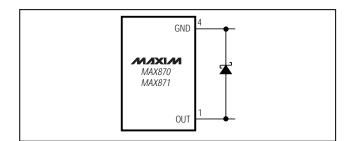


Figure 7. High V- Load Current



**Shutdown Control** If shutdown control is necessary, use the circuit in Figure 8. The output resistance of the MAX870/MAX871 will typically be  $20\Omega$  plus two times the output resistance of the buffer driving IN. The  $0.1\mu$ F capacitor at the IN pin absorbs the transient input currents of the MAX870/MAX871.

The output resistance of the buffer driving the IN pin can be reduced by connecting multiple buffers in parallel. The polarity of the shutdown signal can also be changed by using a noninverting buffer to drive IN.

## Chip Information

TRANSISTOR COUNT: 58 SUBSTRATE CONNECTED TO IN

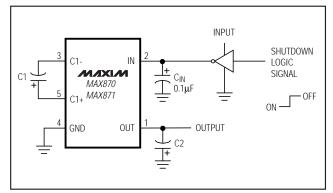
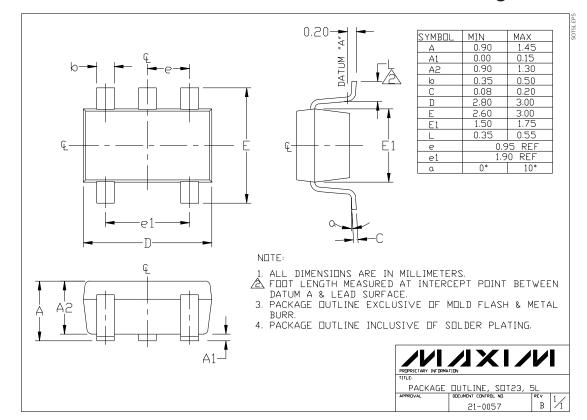


Figure 8. Shutdown Control



## Package Information

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